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LED Display Product Data Sheet LTP-1357AA-NB

Spec No.: DS-30-99-516

Effective Date: 05/31/2000

Revision: -

LITE-ON DCC

RELEASE

BNS-OD-FC001/A4

FEATURES

- * 1.2 inch (30.42 mm) MATRIX HEIGHT.
- * LOW POWER REQUIREMENT.
- * SINGLE PLANE, WIDE VIEWING ANGLE.
- * SOLID STATE RELIABILITY.
- * 5 ×7 ARRAY WITH X-Y SELECT.
- * COMPATIBLE WITH USASCII AND EBCDIC CODES.
- * STACKABLE HORIZONTALLY.
- * CATEGORIZED FOR LUMINOUS INTENSITY.

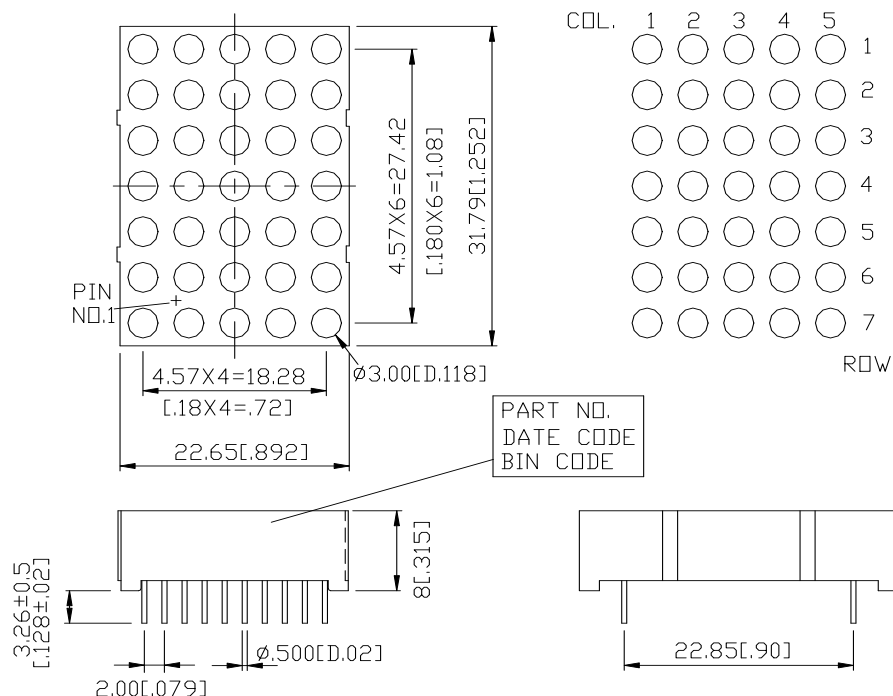
DESCRIPTION

The LTP-1357AA-NB is a 1.2 inch (30.42 mm) matrix height 5 × 7 dot matrix display. This device utilizes green and red orange LED chips, the green LED chips are made from GaP on a transparent GaP substrate , the red orange LED chips are made from GaAsP on a transparent GaP substrate, and has a black face and white dot color.

DEVICE

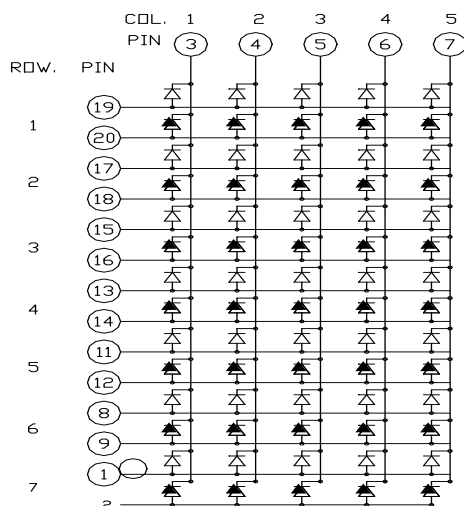
PART NO.	DESCRIPTION
RED ORANGR & GREEN	Cathode Column
LTP-1357AA-NB	Anode Row

PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 mm (0.01") unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM



THE SIGN "△" STANDS FOR GREEN COLOR CHIPS.
 THE SIGN "▲" STANDS FOR ORANGE COLOR CHIPS.

PIN CONNECTION

No.	CONNECTION
1	ANODE ROW.7 GREEN
2	ANODE ROW.7 RED ORANGE
3	CATHODE COLUMN 1
4	CATHODE COLUMN 2
5	CATHODE COLUMN 3
6	CATHODE COLUMN 4
7	CATHODE COLUMN 5
8	ANODE ROW.6 GREEN
9	ANODE ROW.6 RED ORANGE
10	NO CONNECTION
11	CATHODE ROW.5 GREEN
12	CATHODE ROW.5 RED ORANGE
13	ANODE ROW.4 GREEN
14	ANODE ROW.4 RED ORANGE
15	ANODE ROW.3 GREEN
16	ANODE ROW.3 RED ORANGE
17	ANODE ROW.2 GREEN
18	ANODE ROW.2 RED ORANGE
19	ANODE ROW.1 GREEN
20	ANODE ROW.1 RED ORANGE

ABSOLUTE MAXIMUM RATING AT Ta=25°C

GREEN

PARAMETER	MAXIMUM RATING	UNIT
Average Power Dissipation Per Dot	36	mW
Peak Forward Current Per Dot	100	mA
Average Forward Current Per Dot	13	mA
Derating Linear From 25°C Per Dot	0.17	mA/°C
Reverse Voltage Per Segment	5	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature: max 260°C for max 3sec at 1.6mm[1/16inch] below seating plane.		

ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C

GREEN

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I _v	1500	4000		μcd	I _p =80mA 1/16Duty
Peak Emission Wavelength	λ _p		565		nm	I _F =20mA
Spectral Line Half-Width	Δλ		30		nm	I _F =20mA
Dominant Wavelength	λ _d		569		nm	I _F =20mA
Forward Voltage any Dot	V _F		2.1	2.6	V	I _F =20mA
			3.0	3.7		I _F =80mA
Reverse Current any Dot	I _R			100	μA	V _R =5V
Luminous Intensity Matching Ratio	I _v -m			2:1		I _F =10mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

ABSOLUTE MAXIMUM RATING AT Ta=25°C

RED ORANGE

PARAMETER	MAXIMUM RATING	UNIT
Average Power Dissipation Per Dot	36	mW
Peak Forward Current Per Dot	100	mA
Average Forward Current Per Dot	13	mA
Derating Linear From 25°C Per Dot	0.17	mA/°C
Reverse Voltage Per Segment	5	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature: max 260°C for max 3sec at 1.6mm[1/16inch] below seating plane.		

ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C

RED ORANGE

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I _v	1500	4000		μcd	I _p =80mA 1/16Duty
Peak Emission Wavelength	λ _p		630		nm	I _F =20mA
Spectral Line Half-Width	Δλ		40		nm	I _F =20mA
Dominant Wavelength	λ _d		621		nm	I _F =20mA
Forward Voltage any Dot	V _F		2.0	2.6	V	I _F =20mA
			2.6	3.4		I _F =80mA
Reverse Current any Dot	I _R			100	μA	V _R =5V
Luminous Intensity Matching Ratio	I _v -m			2:1		I _F =10mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

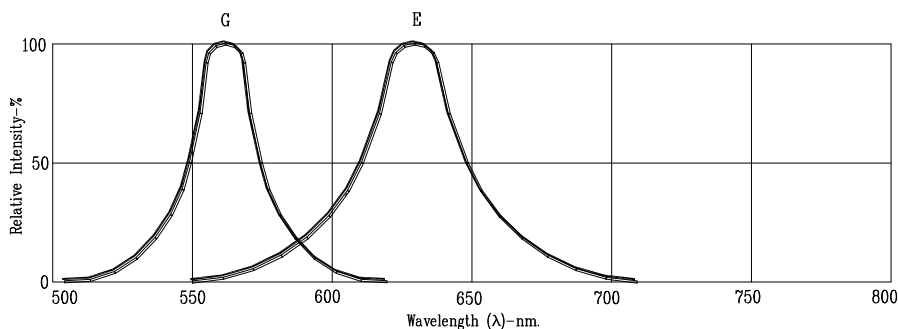


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

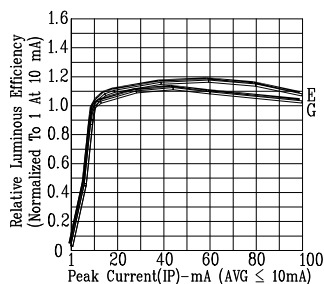


Fig2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT (REFRESH RATE 1KHz)

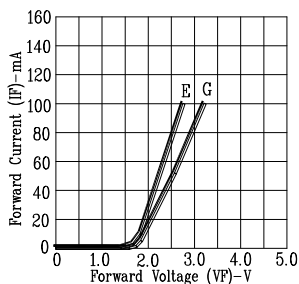


Fig3. FORWARD CURRENT VS. FORWARD VOLTAGE

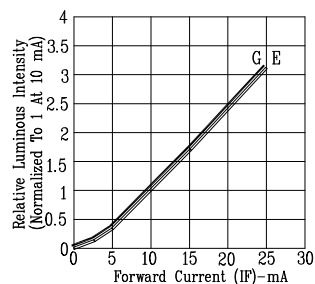


Fig4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

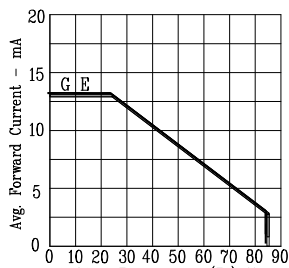


Fig5. MAX. AVERAGE FORWARD CURRENT VS. AMBIENT TEMPERATURE.

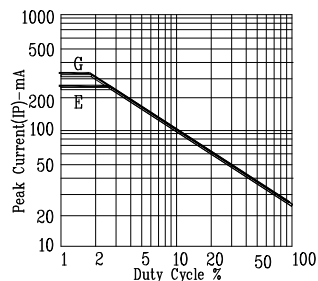


Fig6. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE: G=GREEN E=RED ORANGE